NSN 5961-01-298-2237

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-298-2237 **Inclosure Material:** Glass **Overall Length:** Between 0.160 inches and 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.080 inches and 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage and 28.0 reverse voltage, total rms **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute and 25.00 amperes forward current, average preset **Special Features:** Item must comply with requirements of defense supply center columbus production standard no. Lo4070; reference number differentiating material will be in accordance with naval quality control, manufacturing and testing specifications available at the dla icp **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No